

DUAL-BIT DUAL-SUPPLY BUS TRANSCEIVER WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

Check for Samples: SN74LVC2T45-Q1

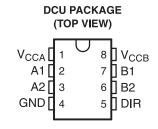
FEATURES

- Qualified for Automotive Applications
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, Both Ports Are in the High-Impedance State
- DIR Input Circuit Referenced to V_{CCA}
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode
 Operation
- Max Data Rates
 - 420 Mbps (3.3-V to 5-V Translation)

DESCRIPTION/ORDERING INFORMATION

210 Mbps (Translate to 3.3 V)
 140 Mbps (Translate to 2.5 V)

- = 140 mbps (Translate to 2.3 V)
- 75 Mbps (Translate to 1.8 V)



This dual-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

The SN74LVC2T45-Q1 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input activate either the B-port outputs or the A-port outputs. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports always is active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ} .

The SN74LVC2T45-Q1 is designed so that the DIR input circuit is supplied by V_{CCA} .

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, both ports are in the high-impedance state.

NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	VSSOP – DCU	Reel of 3000	SN74LVC2T45QDCURQ1	CAWR

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



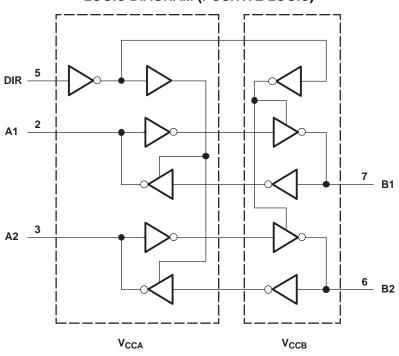
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FUNCTION TABLE⁽¹⁾ (EACH TRANSCEIVER)

INPUT DIR	OPERATION
L	B data to A bus
Н	A data to B bus

(1) Input circuits of the data I/Os always are active.



LOGIC DIAGRAM (POSITIVE LOGIC)



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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impedance or power-c	off state ⁽²⁾	-0.5	6.5	V
V	Voltage range applied to any output in the high or low state ^{(2) (3)}	A port	-0.5	V _{CCA} + 0.5	V
Vo	voltage range applied to any output in the high of low state () ()	B port	-0.5	V _{CCB} + 0.5	v
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCU package		329.4	°C/W
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed. (2)

(3) (4) The value of V_{CC} is provided in the recommended operating conditions table.

The package thermal impedance is calculated in accordance with JESD 51-7.

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RECOMMENDED OPERATING CONDITIONS⁽¹⁾ ⁽²⁾ ⁽³⁾

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V _{CCA}	O				1.65	5.5	V
V _{CCB}	Supply voltage				1.65	5.5	V
			1.65 V to 1.95 V		$V_{CCI} \times 0.65$		
. /	High-level	Data issues (4)	2.3 V to 2.7 V		1.7		
VIH	input voltage	Data inputs ⁽⁴⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCI} \times 0.7$		
			1.65 V to 1.95 V			V _{CCI} × 0.35	
. /	Low-level	Data issues (4)	2.3 V to 2.7 V			0.7	
V _{IL}	input voltage	Data inputs ⁽⁴⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCI} \times 0.3$	
			1.65 V to 1.95 V		V _{CCA} × 0.65		
.,	High-level	DIR	2.3 V to 2.7 V		1.7		.,
VIH	input voltage	(referenced to V_{CCA}) ⁽⁵⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCA} \times 0.7$		
			1.65 V to 1.95 V			$V_{CCA} \times 0.35$	
	Low-level	DIR	2.3 V to 2.7 V			0.7	
V _{IL}	input voltage	(referenced to V_{CCA}) ⁽⁵⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCA} \times 0.3$	
VI	Input voltage				0	5.5	V
Vo	Output voltage				0	V _{CCO}	V
				1.65 V to 1.95 V		-4	
				2.3 V to 2.7 V		-8	A
он	High-level output cu	Irrent		3 V to 3.6 V		-24	mA
				4.5 V to 5.5 V		-32	
				1.65 V to 1.95 V		4	
		rrant		2.3 V to 2.7 V		8	A
I _{OL}	Low-level output cu	rrent		3 V to 3.6 V		24	mA
				4.5 V to 5.5 V		32	
			1.65 V to 1.95 V			20	
		Data inputa	2.3 V to 2.7 V			20	
Δt/Δv	Input transition rise or fall rate	Data inputs	3 V to 3.6 V			10	ns/V
			4.5 V to 5.5 V			5	
		Control input	1.65 V to 5.5 V			5	
T _A	Operating free-air te	emperature			-40	125	°C

V_{CCI} is the V_{CC} associated with the input port.
 V_{CCO} is the V_{CC} associated with the output port.
 All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.



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ELECTRICAL CHARACTERISTICS⁽¹⁾ ⁽²⁾

over recommended operating free-air temperature range (unless otherwise noted)

	METER	TEST CONDITIO		V	v	Т	_A = 25°	С	–40°C to 12	25°C	UNIT
PARA	MEIER	TEST CONDITIO	N9	V _{CCA}	V _{CCB}	MIN	TYP	MAX	MIN	MAX	UNIT
		I _{OH} = −100 μA		1.65 V to 4.5 V	1.65 V to 4.5 V				V _{CCO} - 0.1		
		$I_{OH} = -4 \text{ mA}$		1.65 V	1.65 V				1.2		
V _{ОН}		$I_{OH} = -8 \text{ mA}$ V	$I = V_{IH}$	2.3 V	2.3 V				1.9		V
		I _{OH} = -24 mA		3 V	3 V				2.4		
		I _{OH} = -32 mA		4.5 V	4.5 V				3.8		
		I _{OL} = 100 μA		1.65 V to 4.5 V	1.65 V to 4.5 V					0.1	
		$I_{OL} = 4 \text{ mA}$		1.65 V	1.65 V					0.45	
V _{OL}		I _{OL} = 8 mA V	$I = V_{IL}$	2.3 V	2.3 V					0.3	V
		I _{OL} = 24 mA		3 V	3 V					0.55	
		I _{OL} = 32 mA		4.5 V	4.5 V					0.55	
l _l	DIR	$V_I = V_{CCA}$ or GND		1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±2	μA
	A port			0 V	0 to 5.5 V			±1		±9	A
off	B port	$V_{\rm I}$ or $V_{\rm O}$ = 0 to 5.5 V		0 to 5.5 V	0 V			±1		±9	μA
I _{OZ}	A or B port	$V_{O} = V_{CCO}$ or GND		1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±9	μΑ
				1.65 V to 5.5 V	1.65 V to 5.5 V					4	
I _{CCA}		$V_{I} = V_{CCI} \text{ or } GND, I_{O}$	0 = 0	5 V	0 V					2	μA
				0 V	5 V					-12	
				1.65 V to 5.5 V	1.65 V to 5.5 V					4	
I _{CCB}		$V_{I} = V_{CCI} \text{ or } GND, I_{O}$	0 = 0	5 V	0 V					-12	μA
				0 V	5 V					2	
I _{CCA} +	ССВ	$V_{I} = V_{CCI} \text{ or } GND, I_{O}$	0 = 0	1.65 V to 5.5 V	1.65 V to 5.5 V					4	μA
A 1	A port	One A port at V_{CCA} – DIR at V_{CCA} , B port = open	- 0.6 V,							50	•
ΔI _{CCA}	DIR	DIR at $V_{CCA} - 0.6 V$, B port = open, A port at V_{CCA} or GNI		- 3 V to 5.5 V	3 V to 5.5 V					50	μA
∆I _{CCB}	B port	One B port at V _{CCB} – DIR at GND, A port =		3 V to 5.5 V	3 V to 5.5 V					50	μA
CI	DIR	$V_I = V_{CCA}$ or GND		3.3 V	3.3 V		2.5				pF
C _{io}	A or B port	$V_{O} = V_{CCA/B}$ or GND		3.3 V	3.3 V		6				pF

 $\begin{array}{ll} \mbox{(1)} & V_{CCO} \mbox{ is the } V_{CC} \mbox{ associated with the output port.} \\ \mbox{(2)} & V_{CCI} \mbox{ is the } V_{CC} \mbox{ associated with the input port.} \end{array}$

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{ССВ} = ±0.15	1.8 V V	V _{ССВ} = ±0.2		V _{ССВ} = ±0.3		V _{CCB} = ±0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	^	В	3	21.7	2.2	14.3	1.7	12.3	1.4	11.2	20
t _{PHL}	A	Б	2.8	28.3	2.2	12.5	1.8	11.1	1.7	11	ns
t _{PLH}	В	٥	3	21.7	2.3	20	2.1	19.5	1.9	19.1	20
t _{PHL}	Б	A	2.8	18.3	2.1	16.9	2	16.6	1.8	16.2	ns
t _{PHZ}	DIR	٥	10.6	34.9	10.3	34.5	10.5	34.5	10.7	33.3	20
t _{PLZ}	DIR	A	7.3	23.7	7.5	23.6	7.5	23.5	7	23.4	ns
t _{PHZ}	DIR	В	10	31.9	8.4	18.9	6.5	15.3	4.1	12.6	20
t _{PLZ}	DIR	Б	6.5	23.5	7.2	16.6	4.3	13.7	2.1	11.1	ns
t _{PZH} ⁽¹⁾	חוס	٥		45.2		36.6		33.2		30.2	20
t _{PZL} ⁽¹⁾	DIR	A		50.2		35.8		31.9		28.8	ns
t _{PZH} ⁽¹⁾	חוס	P		45.4		37.9		35.8		34.6	20
t _{PZL} ⁽¹⁾	DIR	В		53.2		47		45.6		44.3	ns

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO	V _{CCB} = ±0.15	1.8 V	V _{CCB} = ±0.2	2.5 V V	V _{CCB} = ±0.3	3.3 V V	V _{CCB} = ±0.5	5 V V	UNIT	
	(INPOT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t _{PLH}	A	В	2.3	20	1.5	12.5	1.3	10.4	1.1	9.1	20	
t _{PHL}	A	Б	2.1	16.9	1.4	11.5	1.3	9.4	0.9	8.6	ns	
t _{PLH}	В	•	2.2	14.3	1.5	12.5	1.4	12	1	11.5	20	
t _{PHL}	Б	A	2.2	12.5	1.4	11.5	1.3	11	0.9	10.2	ns	
t _{PHZ}	DIR	•	6.6	21.1	7.1	20.8	6.8	20.8	5.2	20.5	20	
t _{PLZ}	DIR	A	5.3	16.6	5.2	16.5	4.9	16.3	4.8	16.3	ns	
t _{PHZ}		P	10.7	31.9	8.1	17.9	5.8	14.5	3.5	11.6		
t _{PLZ}	DIR	В	7.8	22.9	6.2	15.2	3.6	12.9	1.4	11.2	ns	
t _{PZH} ⁽¹⁾	DID	•		37.2		27.7		24.9		21.7		
t _{PZL} ⁽¹⁾	DIR	A		44.4		29.4		25.5		21.8	ns	
t _{PZH} ⁽¹⁾	DID	DID	Р		28.6		29		26.7		25.4	20
t _{PZL} ⁽¹⁾	DIR	В		38		32.3		30.2		29.1	ns	

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, V_{CCA} = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{ССВ} = ±0.15	1.8 V 5 V	V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = ±0.3		V _{CCB} = ±0.5		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	МАХ	
t _{PLH}	•	В	2.1	19.5	1.4	12	0.7	9.6	0.7	8.4	~~~
t _{PHL}	A	Б	2	16.6	1.3	11	0.8	9	0.7	8	ns
t _{PLH}	В	•	1.7	12.3	1.3	10.4	0.7	9.8	0.6	9.4	~~~
t _{PHL}	Б	A	1.8	11.1	1.3	9.4	0.8	9	0.7	8.5	ns
t _{PHZ}	DIR	٨	5	14.9	5.1	14.8	5	14.8	5	14.4	20
t _{PLZ}	DIK	A	3.4	12.4	3.7	12.4	3.9	12.1	3.3	11.8	ns
t _{PHZ}	DIR	В	11.2	31.3	8	17.7	5.8	14.4	2.9	11.4	20
t _{PLZ}	DIR	D	9.4	21.7	5.6	15.3	4.3	12.3	1	9.6	ns
t _{PZH} ⁽¹⁾	DID	•		34		25.7		22.1		19	
t _{PZL} ⁽¹⁾	DIR	A		42.4		27.1		23.4		19.9	ns
t _{PZH} ⁽¹⁾	חוס	Р		31.9		24.4		21.9		20.2	~~~
t _{PZL} ⁽¹⁾	DIR	В		31.5		25.8		23.8		22.4	ns

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{CCA} = 5 V \pm 0.5 V$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V _{CCB} = ±0.15	1.8 V	V _{CCB} = ±0.2	2.5 V V	V _{CCB} = ±0.3	3.3 V V	V _{CCB} = ±0.5		UNIT			
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX				
t _{PLH}	А	В	1.9	19.1	1	11.5	0.6	9.4	0.5	7.9	20			
t _{PHL}	A	В	1.8	16.2	0.9	10.2	0.7	8.5	0.5	7.5	ns			
t _{PLH}	В	•	1.4	11.2	1	9.1	0.7	8.4	0.5	7.9	20			
t _{PHL}	Б	A	1.7	11	0.9	8.6	0.7	8	0.5	7.5	ns			
t _{PHZ}	DIR	•	2.9	12.2	2.9	11.9	2.8	11.9	2.2	11.8	20			
t _{PLZ}	DIR	A	1.4	10.9	1.3	10.7	0.7	10.7	0.7	10.6	ns			
t _{PHZ}	סוס	В	11.2	30.1	7.2	17.9	5.8	14.1	1.3	11.3				
t _{PLZ}	DIR	D	8.4	20.9	5	15	4	11.7	1	9.6	ns			
t _{PZH} ⁽¹⁾	חוס	•		32.1		24.1		20.1		18.5	20			
t _{PZL} ⁽¹⁾	DIR	A		41.1		26.5		22.1		18.8	ns			
t _{PZH} ⁽¹⁾	DID	DIR	DID	DID	В		30		22.2		20.1		18.5	20
t _{PZL} ⁽¹⁾	DIR	В		28.4		22.1		22.4		19.3	ns			

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.

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OPERATING CHARACTERISTICS

$T_{A} = 25^{\circ}$	С						
PARAMETER		TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.8 V	V _{CCA} = V _{CCB} = 2.5 V	V _{CCA} = V _{CCB} = 3.3 V	V _{CCA} = V _{CCB} = 5 V	UNIT
		CONDITIONS	TYP	TYP	TYP	ТҮР	
C (1)	A-port input, B-port output	$C_L = 0 \text{ pF},$	3	4	4	4	~ [
C _{pdA} ⁽¹⁾	B-port input, A-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	18	19	20	21	- pF
c (1)	A-port input, B-port output	$C_L = 0 \text{ pF},$	18	19	20	21	- 5
C _{pdB} ⁽¹⁾	B-port input, A-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	3	4	4	4	- pF

(1) Power dissipation capacitance per transceiver





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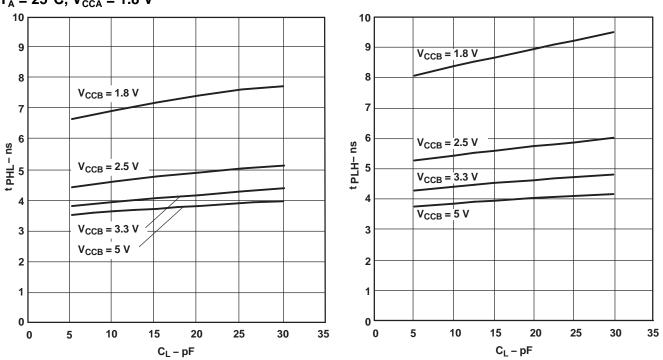
Power-Up Considerations

A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies. To guard against such power-up problems, take the following precautions:

- 1. Connect ground before any supply voltage is applied.
- 2. Power up V_{CCA} .
- 3. V_{CCB} can be ramped up along with or after V_{CCA} .

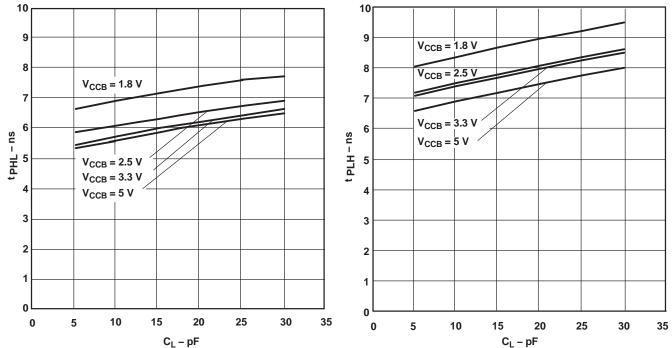
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TYPICAL CHARACTERISTICS



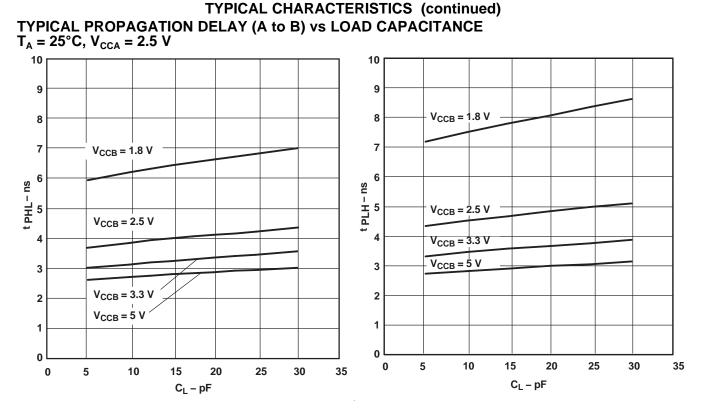
TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 1.8 V

TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 1.8 V

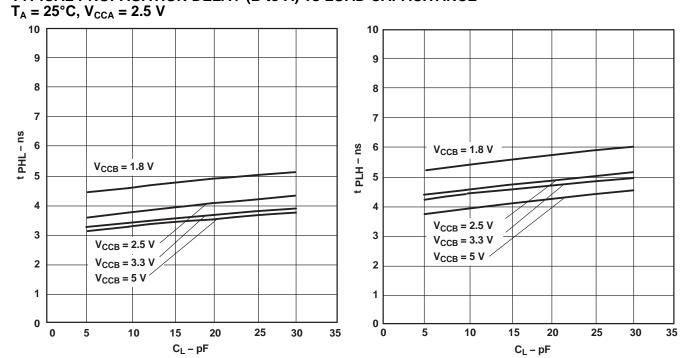




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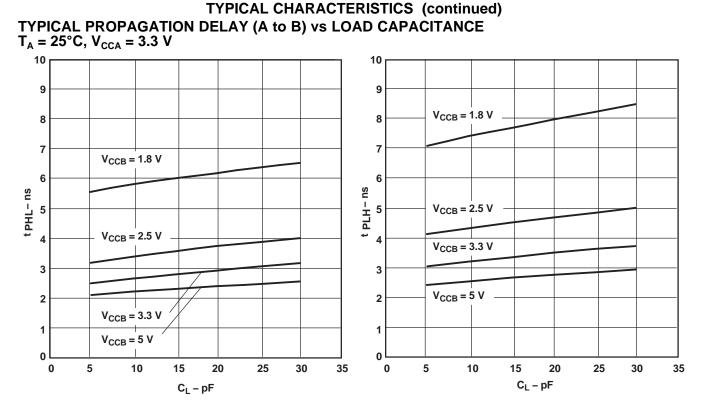
TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE

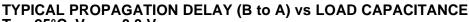


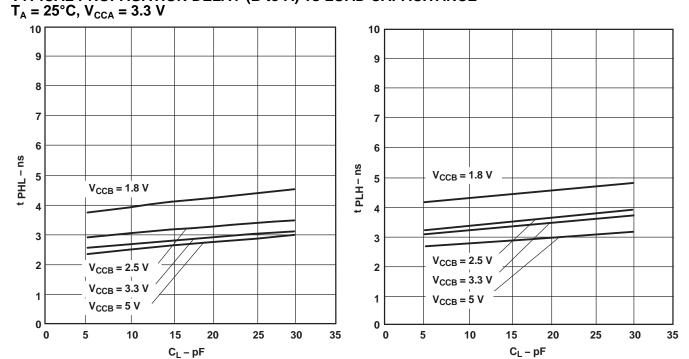
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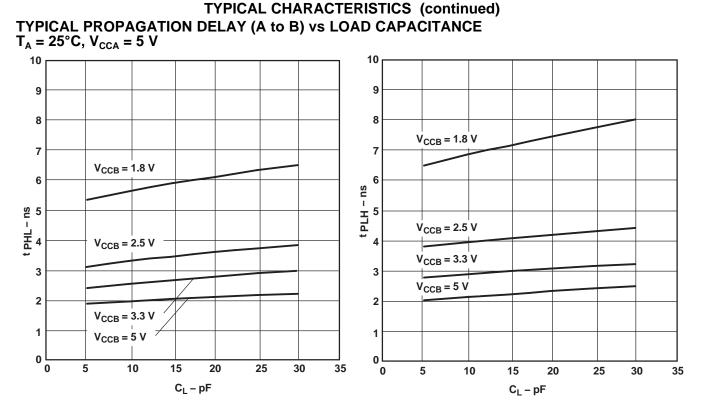




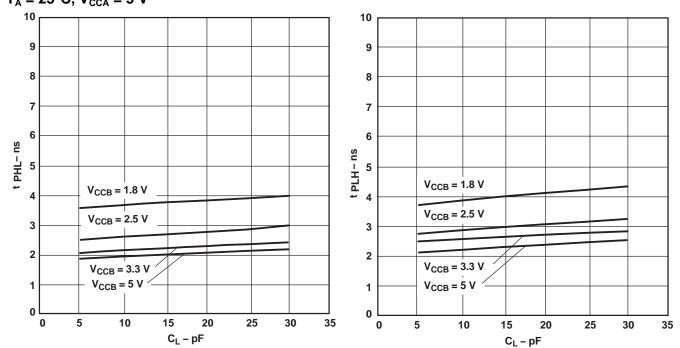




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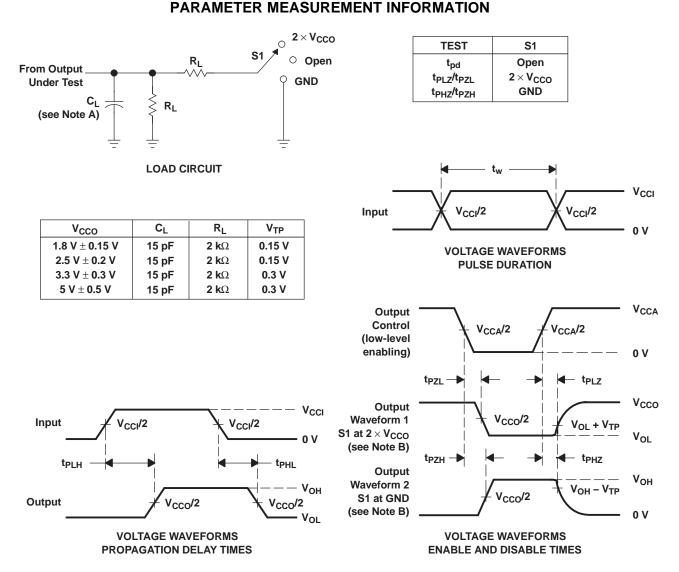


TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE $T_A = 25^{\circ}$ C, $V_{CCA} = 5$ V





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NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , dv/dt \geq 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

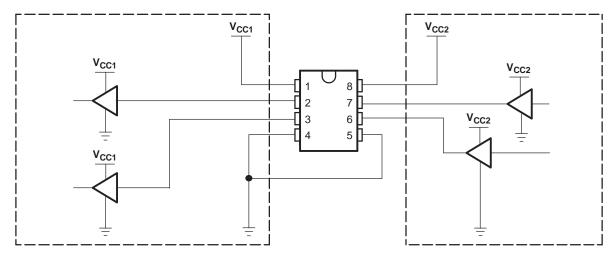
Figure 1. Load Circuit and Voltage Waveforms



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APPLICATION INFORMATION

The following shows an example of the SN74LVC2T45-Q1 being used in a unidirectional logic level-shifting application.



SYSTEM-1

SYSTEM-2

PIN	NAME	FUNCTION	DESCRIPTION
1	V _{CCA}	V _{CC1}	SYSTEM-1 supply voltage (1.65 V to 5.5 V)
2	A1	OUT1	Output level depends on V_{CC1} voltage.
3	A2	OUT2	Output level depends on V _{CC1} voltage.
4	GND	GND	Device GND
5	DIR	DIR	GND (low level) determines B-port to A-port direction.
6	B2	IN2	Input threshold value depends on V _{CC2} voltage.
7	B1	IN1	Input threshold value depends on V _{CC2} voltage.
8	V _{CCB}	V _{CC2}	SYSTEM-2 supply voltage (1.65 V to 5.5 V)

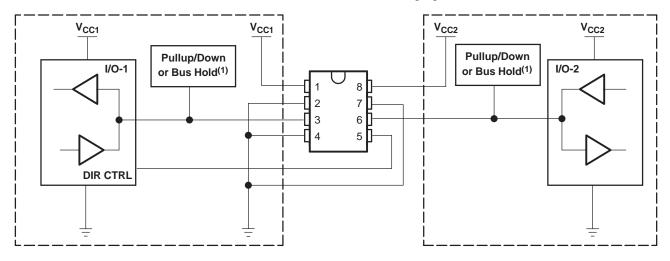
Figure 2. Unidirectional Logic Level-Shifting Application



SCES818-SEPTEMBER 2010

APPLICATION INFORMATION

Figure 3 shows the SN74LVC2T45-Q1 being used in a bidirectional logic level-shifting application. Since the SN74LVC2T45-Q1 does not have an output-enable (OE) pin, the system designer should take precautions to avoid bus contention between SYSTEM-1 and SYSTEM-2 when changing directions.



SYSTEM-1

SYSTEM-2

The following table shows data transmission from SYSTEM-1 to SYSTEM-2 and then from SYSTEM-2 to SYSTEM-1.

STATE	DIR CTRL	I/O-1	I/O-2	DESCRIPTION
1	Н	Out	In	SYSTEM-1 data to SYSTEM-2
2	Н	Hi-Z	Hi-Z	SYSTEM-2 is getting ready to send data to SYSTEM-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on pullup or pulldown. ⁽¹⁾
3	L	Hi-Z	Hi-Z	DIR bit is flipped. I/O-1 and I/O-2 still are disabled. The bus-line state depends on pullup or pulldown. ⁽¹⁾
4	L	In	Out	SYSTEM-2 data to SYSTEM-1

(1) SYSTEM-1 and SYSTEM-2 must use the same conditions, i.e., both pullup or both pulldown.

Figure 3. Bidirectional Logic Level-Shifting Application

Enable Times

Calculate the enable times for the SN74LVC2T45-Q1 using the following formulas:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{P71} (DIR to B) = t_{PH7} (DIR to A) + t_{PH1} (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the SN74LVC2T45-Q1 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74LVC2T45QDCURQ1	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SN74LVC2T45-Q1 :

• Catalog: SN74LVC2T45

• Enhanced Product: SN74LVC2T45-EP

NOTE: Qualified Version Definitions:

PACKAGE OPTION ADDENDUM



30-Jan-2012

• Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

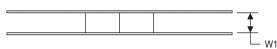
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

Texas Instruments





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2T45QDCURQ1	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

28-Jan-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2T45QDCURQ1	US8	DCU	8	3000	202.0	201.0	28.0

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



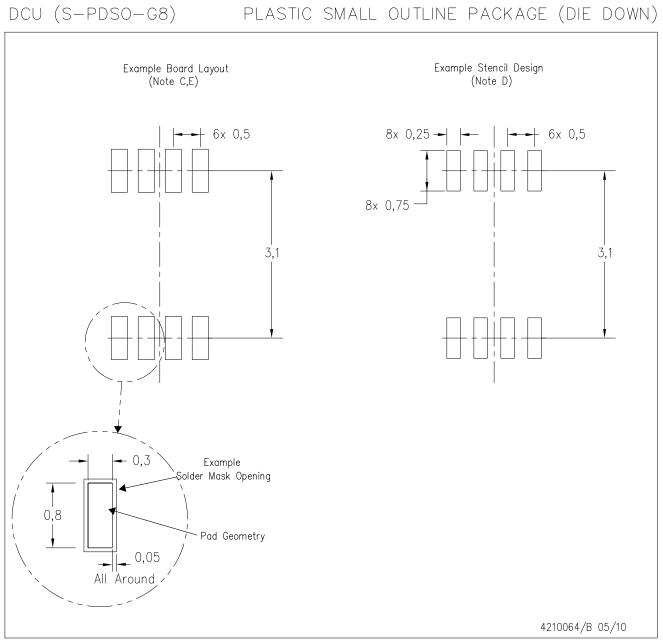
NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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